FAIRCHILD SEMICONDUCTOR®

October 2005

H11AA1, H11AA3, H11AA2, H11AA4
AC Input/Phototransistor Optocouplers

Features

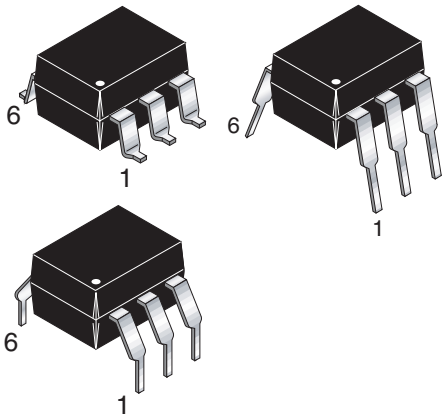
- Bi-polar emitter input
- Built-in reverse polarity input protection
- Underwriters Laboratory (UL) recognized – File #E90700
- VDE approved – File #E94766 (ordering option '300')

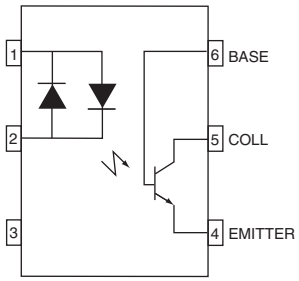
Applications

- AC line monitor
- Unknown polarity DC sensor
- Telephone line interface

Description

The H11AAX series consists of two gallium-arsenide infrared emitting diodes connected in inverse parallel driving a single silicon phototransistor output.





Parameter	Symbol	Device	Value	Units
TOTAL DEVICE				
Storage Temperature	T_{STG}	All	-55 to +150	°C
Operating Temperature	T_{OPR}	All	-55 to +100	°C
Lead Solder Temperature	T_{SOL}	All	260 for 10 sec	°C
Total Device Power Dissipation	P_D	All	350	mW
Derate Linearly From 25°C			4.6	mW/°C
EMITTER				
Continuous Forward Current	I_F	All	100	mA
Forward Current - Peak (1 µs pulse, 300 pps)	$I_{F(pk)}$	All	±1.0	A
LED Power Dissipation	P_D	All	200	mW
Derate Linearly From 25°C			2.6	mW/°C
DETECTOR				
Detector Power Dissipation	P_D	All	300	mW
Derate above 25°C			4.0	mW/°C

Electrical Characteristics (T_A = 25°C Unless otherwise specified.)

Individual Component Characteristics

Parameter	Test Conditions	Symbol	Device	Min	Typ	Max	Unit
EMITTER							
Input Forward Voltage	I_F = ±10 mA	V_F	All		1.2	1.5	V
Capacitance	V_F = 0 V, f = 1.0 MHz	C_J	All		80		pF
DETECTOR							
Breakdown Voltage Collector to Emitter	I_C = 1.0 mA, I_F = 0	BV_{CEO}	All	30			V
Collector to Base	I_C = 100 µA, I_F = 0	BV_{CBO}	All	70			V
Emitter to Base	I_E = 100 µA, I_F = 0	BV_{EBO}	All	5			V
Emitter to Collector	I_E = 100 µA, I_F = 0	BV_{ECO}	All	7			V
Leakage Current Collector to Emitter	V_{CE} = 10 V, I_F = 0	I_{CEO}	H11AA1,3,4			50	nA
			H11AA2			200	
Capacitance Collector to Emitter	V_{CE} = 0, f = 1 MHz	C_{CE}	All		10		pF
Collector to Base	V_{CE} = 0, f = 1 MHz	C_{CB}	All		80		pF
Emitter to Base	V_{CE} = 0, f = 1 MHz	C_{EB}	All		15		pF

Transfer Characteristics (T_A = 25°C Unless otherwise specified.)

Characteristics	Test Conditions	Symbol	Device	Min	Typ	Max	Units
Current Transfer Ratio, Collector to Emitter	I_F = ±10 mA, V_{CE} = 10 V	CTR_{CE}	H11AA4	100			%
			H11AA3	50			
			H11AA1	20			
			H11AA2	10			
Current Transfer Ratio, Symmetry	I_F = ±10 mA, V_{CE} = 10 V (Figure.8)		All	.33		3.0	
Saturation Voltage Collector to Emitter	I_F = ±10 mA, I_{CE} = 0.5 mA	$V_{CE(SAT)}$	All			.40	V

Isolation Characteristics

Characteristic	Test Conditions	Symbol	Min	Typ	Max	Units
Package Capacitance input/output	V_{I-O} = 0, f = 1 MHz	C_{I-O}		0.7		pF
Isolation Voltage	f = 60 Hz, t = 1 min.	V_{ISO}	5300			VAC(RMS)
Isolation Resistance	V_{I-O} = 500 VDC	R_{ISO}	1011			Ω

Fig. 1 Input Voltage vs. Input Current

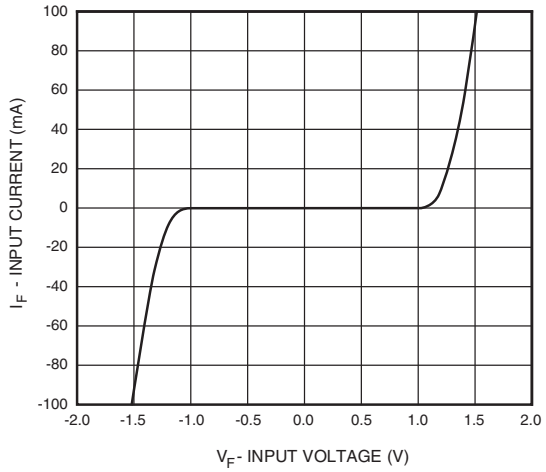


Fig. 2 Normalized CTR vs. Forward Current

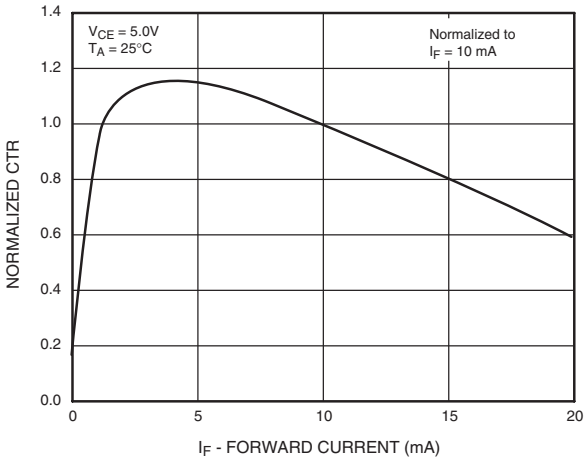


Fig. 3 Normalized CTR vs. Ambient Temperature

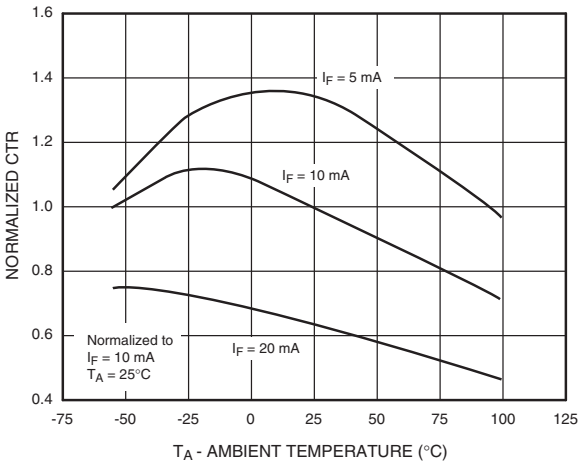


Fig. 4 CTR vs. RBE (Unsaturated)

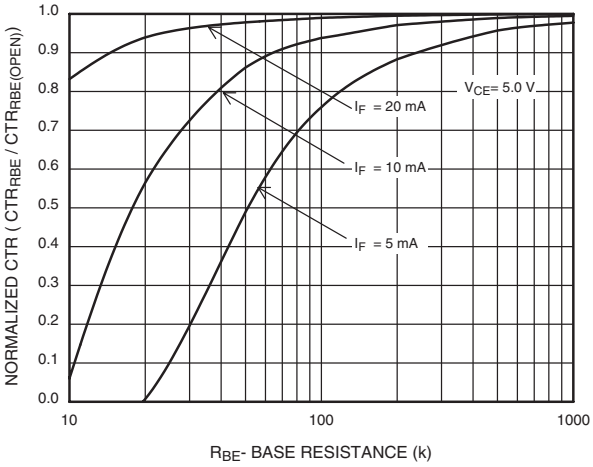


Fig. 5 CTR vs. RBE (Saturated)

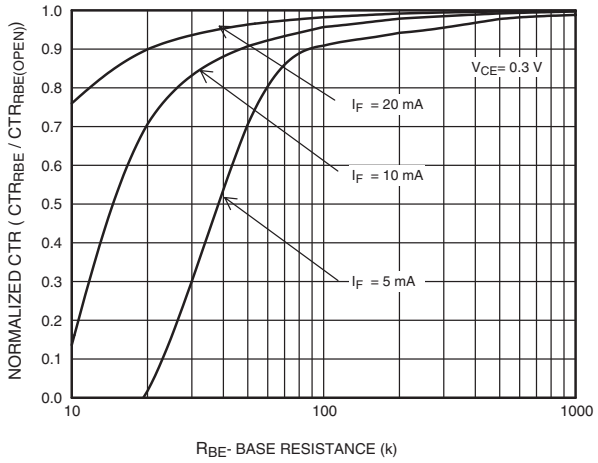


Fig. 6 Collector-Emitter Saturation Voltage vs Collector Current

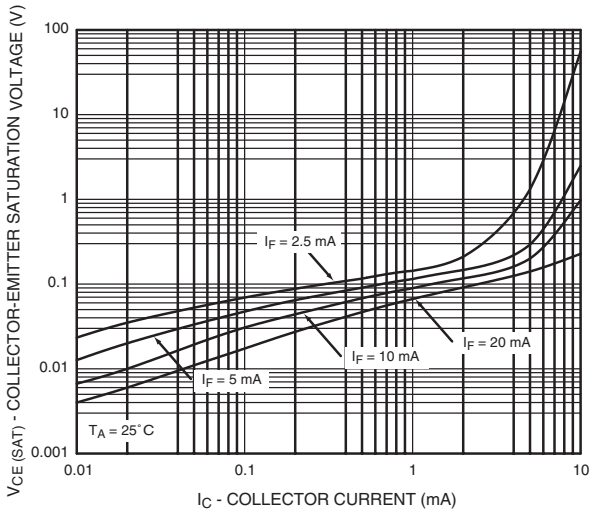


Fig. 7 Switching Speed vs. Load Resistor

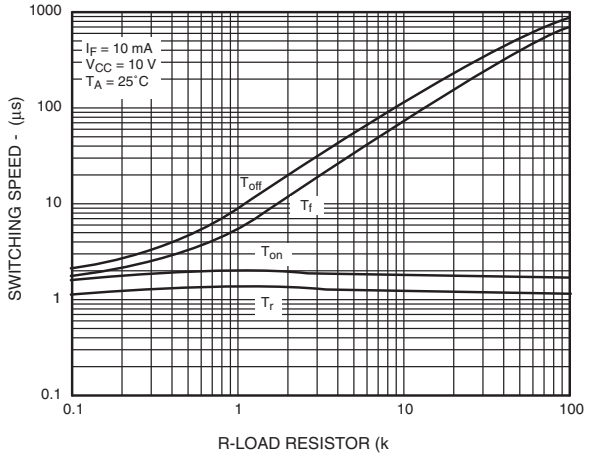


Fig. 8 Normalized t_{on} vs. R_{BE}

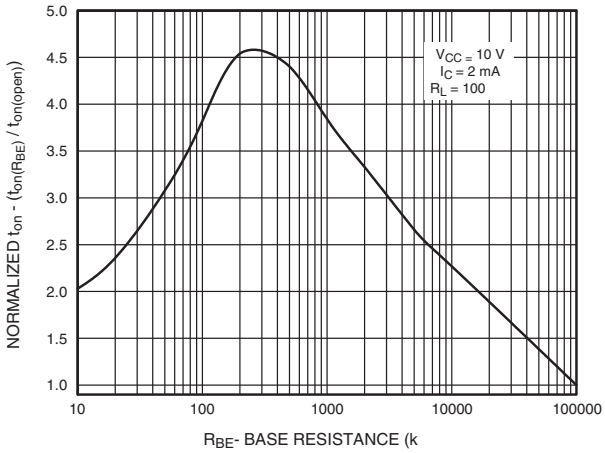


Fig. 9 Normalized t_{off} vs. R_{BE}

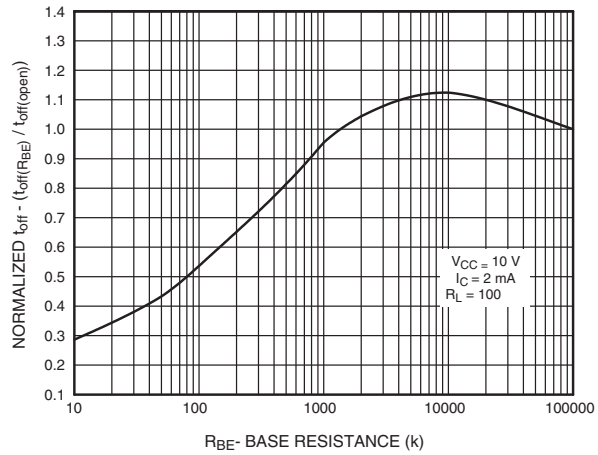


Fig. 10 Dark Current vs. Ambient Temperature

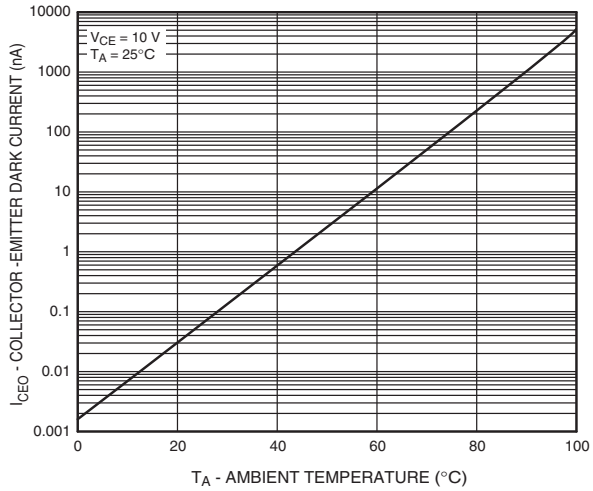
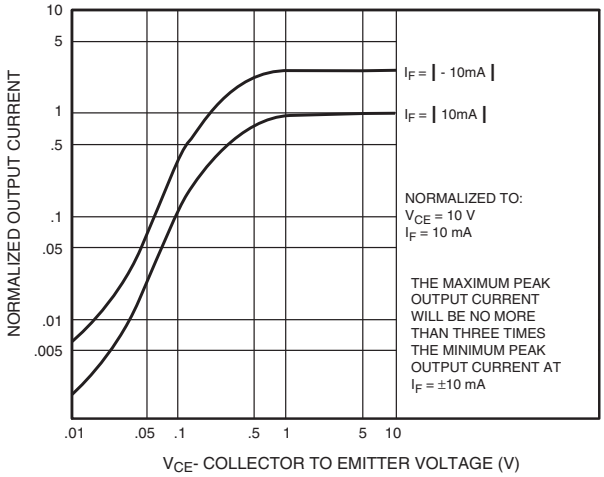
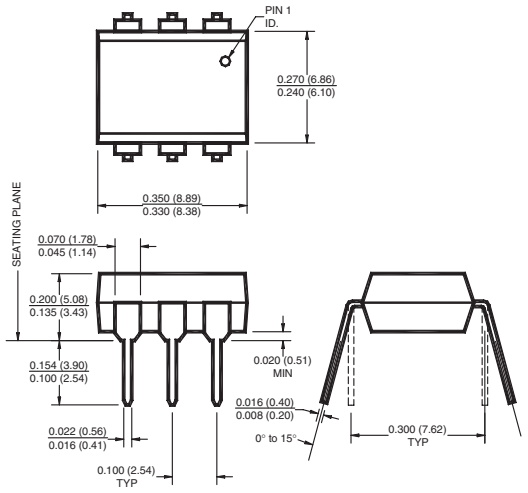


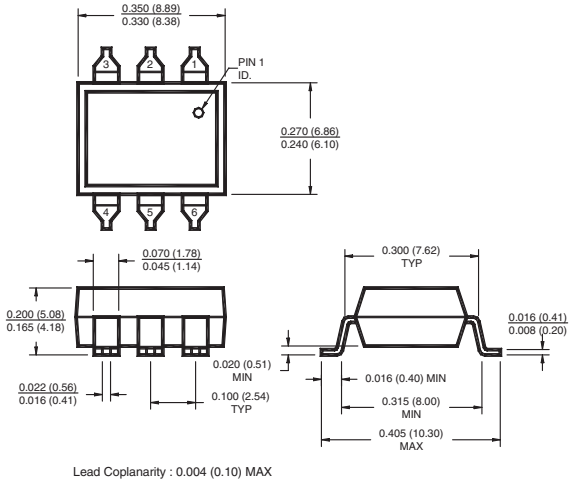
Fig. 11 Output Symmetry Characteristics



Package Dimensions (Through Hole)

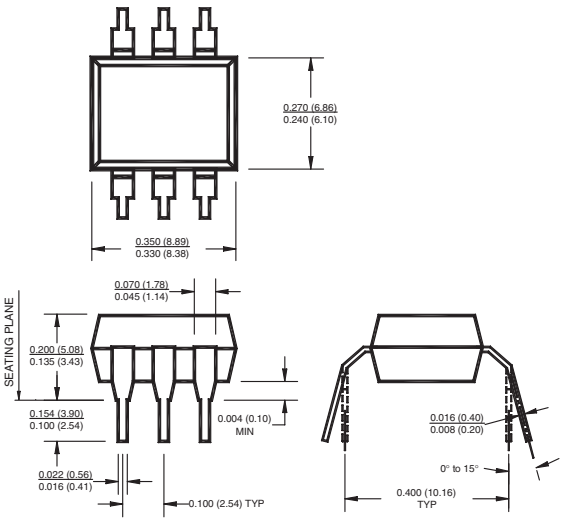


Package Dimensions (Surface Mount)

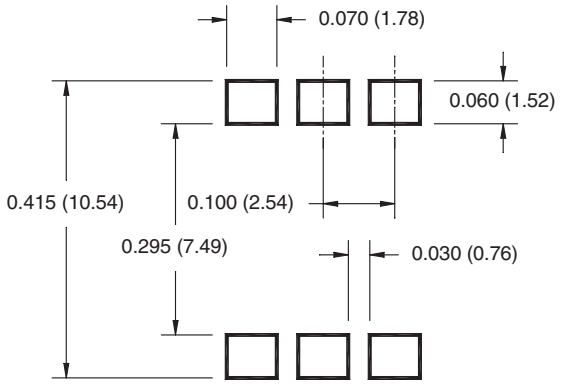


Lead Coplanarity : 0.004 (0.10) MAX

Package Dimensions (0.4"Lead Spacing)



Recommended Pad Layout for Surface Mount Leadform



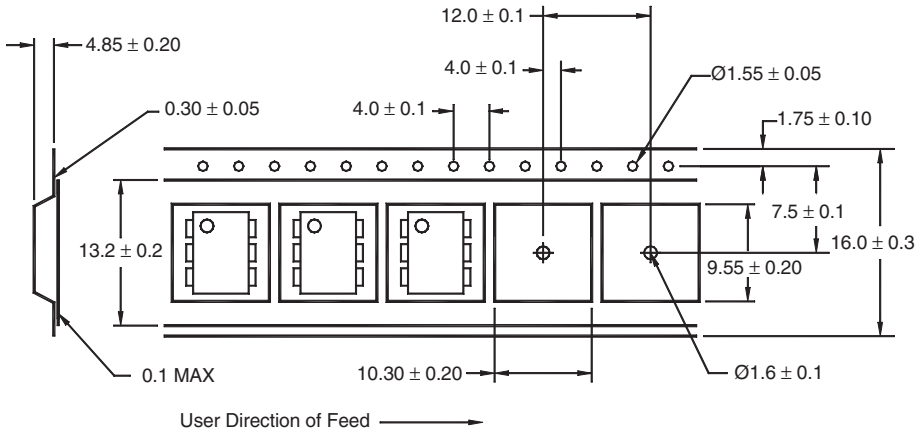
Note

All dimensions are in inches (millimeters)

Ordering Information

Option	Order Entry Identifier	Description
S	.S	Surface Mount Lead Bend
SD	.SD	Surface Mount; Tape and Reel
W	.W	0.4” Lead Spacing
300	.300	VDE 0884
300W	.300W	VDE 0884, 0.4” Lead Spacing
3S	.3S	VDE 0884, Surface Mount
3SD	.3SD	VDE 0884, Surface Mount, Tape and Reel

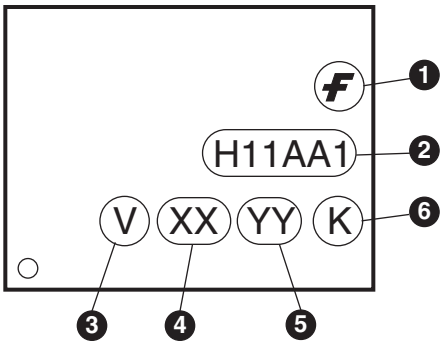
Carrier Tape Specifications (“D” Taping Orientation)



Note

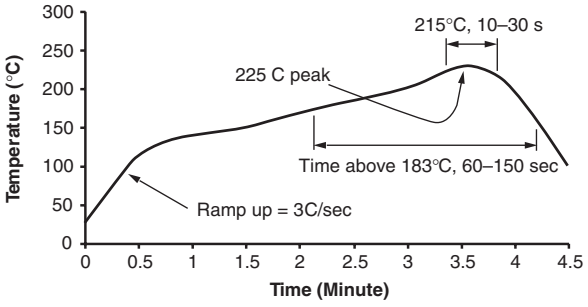
All dimensions are in millimeters

Marking Information



Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	Two digit year code, e.g., ‘03’
5	Two digit work week ranging from ‘01’ to ‘53’
6	Assembly package code

Reflow Profile (Black Package, No Suffix)



- Peak reflow temperature: 225°C (package surface temperature)
- Time of temperature higher than 183°C for 60–150 seconds
- One time soldering reflow is recommended

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2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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